

isc N-Channel MOSFET Transistor

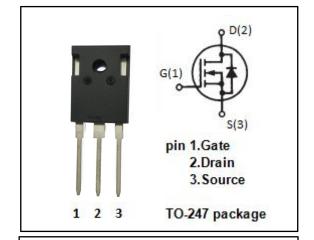
STW36N55M5

• FEATURES

- With TO-247 packaging
- · High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



- Power supply
- Switching applications

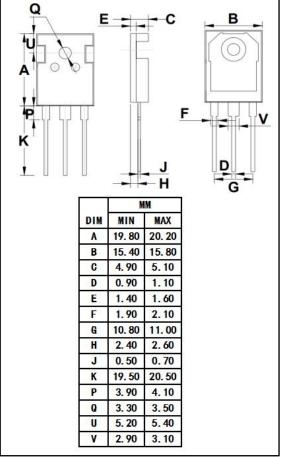


• ABSOLUTE MAXIMUM RATINGS($T_a=25^{\circ}C$)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	550	V	
V _{GSS}	Gate-Source Voltage	±25	V	
I _D	Drain Current-Continuous@T _C =25℃ 33			
I _{DM}	Drain Current-Single Pulsed	Α		
P _D	Total Dissipation	190	W	
T _j	Operating Junction Temperature 150		$^{\circ}$	
T _{stg}	Storage Temperature -55~150		$^{\circ}$	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.66	°C/W



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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1.0mA	550			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	3.0		5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =16.5A			80	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±25V;V _{DS} = 0V			±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 550V; V _{GS} = 0V;Tc=25℃ Tc=125℃			1 100	μА
V _{SDF}	Diode forward voltage	I _{SD} = 33A, V _{GS} = 0 V			1.5	V

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